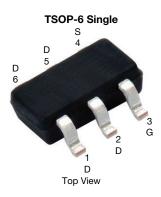




Automotive P-Channel 60 V (D-S) 175 °C MOSFET



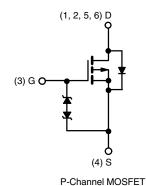
PRODUCT SUMMARY				
V _{DS} (V)	-60			
$R_{DS(on)}$ (Ω) at $V_{GS} = -10 \text{ V}$	0.095			
$R_{DS(on)}$ (Ω) at $V_{GS} = -4.5 \text{ V}$	0.135			
I _D (A)	-5.3			
Configuration	Single			
Package	TSOP-6			

Marking Code: 9K

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Typical ESD protection 800 V
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free and halogen-free	SQ3427CEEV (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS ($T_C =$	25 °C, unles	s otherwise noted	1)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	-60	V	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current	T _C = 25 °C	- I _D	-5.3		
	T _C = 125 °C		-3		
Continuous Source Current (Diode Conduction)		I _S	-6.3	Α	
Pulsed Drain Current ^a		I _{DM}	-21		
Single Pulse Avalanche Current	J 0.1 mal J	I _{AS}	-21		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	22	mJ	
Maximum Power Dissipation	T _C = 25 °C	D	5	W	
	T _C = 125 °C	P_{D}	1.6		
Operating Junction and Storage Temperature Range		T _J , T _{stq}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount b	R_{thJA}	110	°C/W	
Junction-to-Foot (Drain)		R_{thJF}	30	C/ VV	

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)



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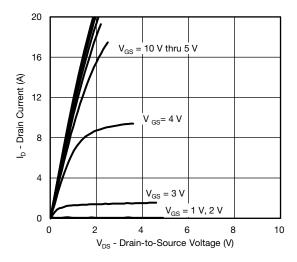
PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0, I _D = -250 μA		-60	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-1.5	-2	-2.5	V	
Coto Course Legisone		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-		± 10	mA	
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$		-	-	± 2		
	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -60 V	-	-	-1		
Zero Gate Voltage Drain Current		V _{GS} = 0 V	V _{DS} = -60 V, T _J = 125 °C	-	-	-50	μA	
-		V _{GS} = 0 V	V _{DS} = -60 V, T _J = 175 °C	-	-	-150		
On-State Drain Current a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≤ -5 V	-10	-	-	Α	
Duti Ou and Ou Old Breisland	R _{DS(on)}	V _{GS} = -10 V	I _D = -4.5 A	-	0.079	0.095	Ω	
		V _{GS} = -10 V	I _D = -4.5 A, T _J = 125 °C	-	-	0.148		
Drain-Source On-State Resistance ^a		V _{GS} = -10 V	I _D = -4.5 A, T _J = 175 °C	-	-	0.178		
		V _{GS} = -4.5 V	I _D = -3.5 A	-	0.112	0.135		
Forward Transconductance ^a	9 _{fs}	V _{DS} = -15 V, I _D = -4 A		-	9	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}		V _{DS} = -30 V, f = 1 MHz	-	700	1000	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	90	120		
Reverse Transfer Capacitance	C _{rss}			-	50	75		
Total Gate Charge ^c	Qg			-	15.3	22		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = -10 \text{ V}$	$V_{DS} = -30 \text{ V}, I_{D} = -5 \text{ A}$	-	2.5	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	5.4	-		
Gate Resistance	Rg	f = 1 MHz		2.7	5.4	8.1	Ω	
Turn-On Delay Time ^c	t _{d(on)}				8	12		
Rise Time ^c	t _r	V_{DD} = -30 V, R_L = 6 Ω $I_D \cong$ -5 A, V_{GEN} = -10 V, R_g = 1 Ω		-	24	35	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	26	38		
Fall Time ^c	t _f			-	33	50		
Source-Drain Diode Ratings and Charac	teristics ^b							
Pulsed Current ^a	I _{SM}			-	-	-21	Α	
Forward Voltage	V_{SD}	I _F = -1.6 A, V _{GS} = 0 V		-	-0.8	-1.2	V	
Body diode reverse recovery time	t _{rr}			-	24	48	ns	
Body diode reverse recovery charge	Q _{rr}	I _F = -1.7 A, di/dit = 100 A/μs		-	29	58	nC	
Reverse recovery fall time	t _a			-	21	-		
Reverse recovery rise time	t _b			-	3	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			_	-2.97	-	Α	

Notes

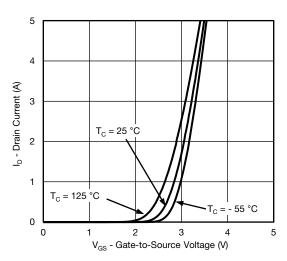
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

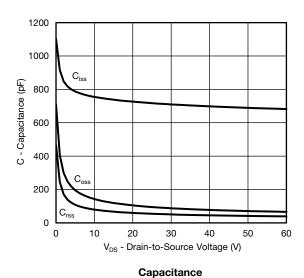


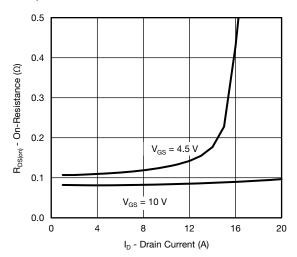


Output Characteristics

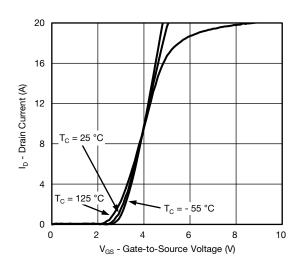


Transfer Characteristics

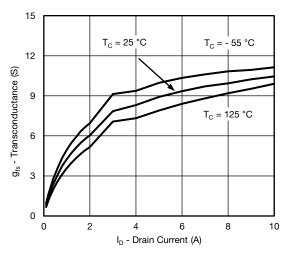




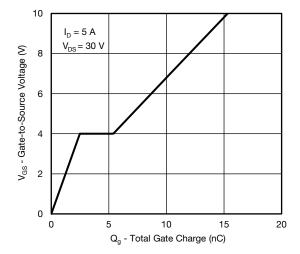
On-Resistance vs. Drain Current and Gate Voltage



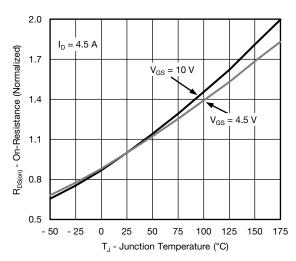
Transfer Characteristics



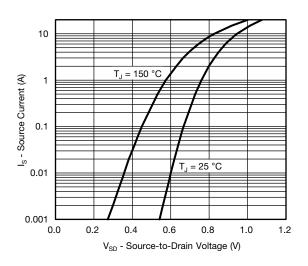




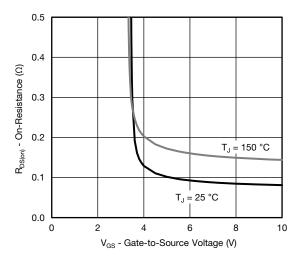
Gate Charge



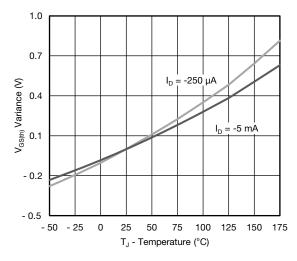
On-Resistance vs. Junction Temperature



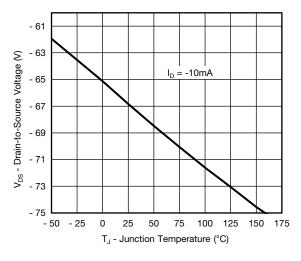
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

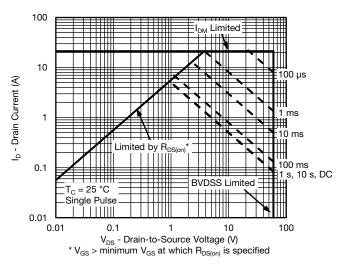


Threshold Voltage

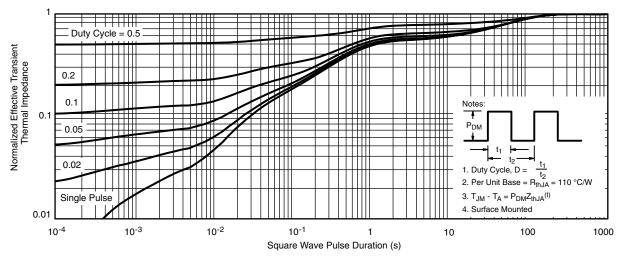


Drain-to-Source Voltage vs. Junction Temperature



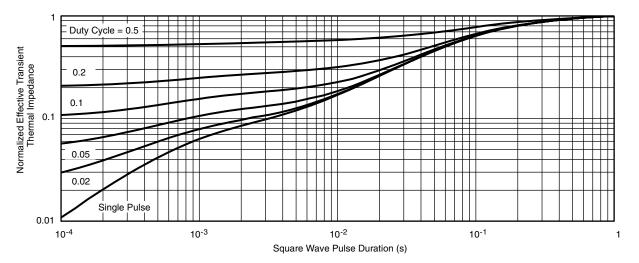


Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient





Normalized Thermal Transient Impedance, Junction-to-Foot

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